# General purpose transistors (dual transistors)

# **EMT18 / UMT18N / IMT18**

#### Features

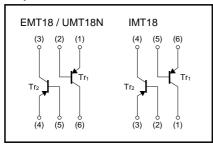
- 1) Two 2SA2018 chips in a EMT package.
- 2) Mounting possible with EMT3 or UMT3 or SMT3 automatic mounting machines.
- Transistor elements are independent, eliminating interference.

#### Structure

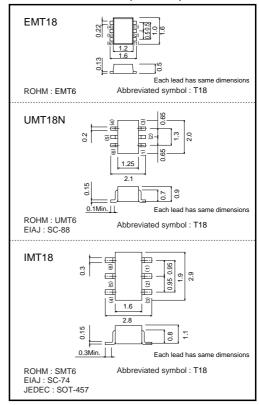
Epitaxial planar type NPN silicon transistor

The following characteristics apply to both Tr<sub>1</sub> and Tr<sub>2</sub>.

# ●Equivalent circuit



## ●External dimensions (Unit: mm)



# ● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol		Limits	Unit
Collector-base voltage	V <sub>CBO</sub>		-15	V
Collector-emitter voltage	Vceo		-12	V
Emitter-base voltage	V <sub>EBO</sub>		-6	V
Collector current		lc	-500	mA
Collector current	ICP		1.0 *1	Α
Power dissipation		EMT6	150 (TOTAL)*2	mW
	Pc	UMT6	150 (TOTAL)	
		SMT6	300 (TOTAL)*3	
Junction temperature	Tj		150	°C
Storage temperature	Tstg		-55 to +150	°C

- \*1 Single pulse Pw=1ms
- \*2 120mW per element must not be exceeded.
- \*3 200mW per element must not be exceeded.

# ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	-15	_	_	٧	I <sub>C</sub> = -10μA	
Collector-emitter breakdown voltage	BVceo	-12	_	_	V	I <sub>C</sub> = -1mA	
Emitter-base breakdown voltage	ВУево	-6	_	_	V	I <sub>E</sub> = -10μA	
Collector cutoff current	Ісво	_	_	-0.1	μΑ	V <sub>CB</sub> = -15V	
Emitter cutoff current	ІЕВО	_	_	-0.1	μΑ	Vcb=-6V	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	_	-100	-250	mV	I <sub>C</sub> / I <sub>B</sub> = -200mA / -10mA	
DC current transfer ratio	hfe	270	_	680	_	Vc=-2V, Ic=-10mA	
Transition frequency	f⊤	_	260	_	MHz	V <sub>CE</sub> = -2V, I <sub>E</sub> =10mA, f=100MHz	
Output capacitance	Cob	_	6.5	_	pF	V <sub>CB</sub> = -10V, I <sub>E</sub> =0A, f=1MHz	

# ●Packaging specifications and hFE

	Package name		Taping	
Type	Code	T2R	TR	T110
	Basic ordering unit (pieces)	8000	3000	3000
EMT18		0	-	_
UMT18N		_	0	_
IMT18		İ	_	0

#### •Electrical characteristic curves

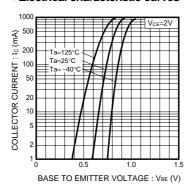


Fig.1 Grounded Emitter Propagation Characteristics

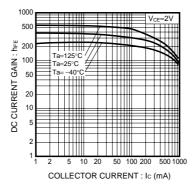


Fig.2 DC Current Gain vs. Collector Current

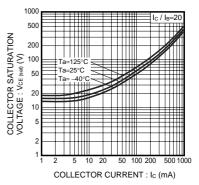


Fig.3 Collector-Emitter Saturation Voltage vs. Collector Current (I)

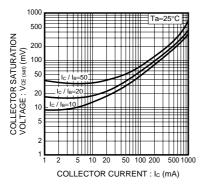


Fig.4 Collector-Emitter Saturation Voltage vs. Collector Current (II)

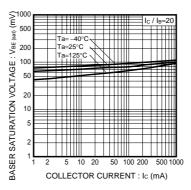


Fig.5 Base-Emitter Saturation Voltage vs.Collecter Current

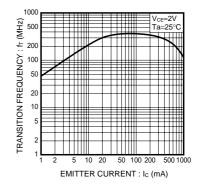


Fig.6 Gain Bandwidth Product vs. Emitter Current

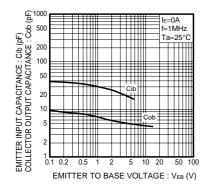


Fig.7 Collector Output Capacitance vs. Collector-Base Voltage Emitter Input Capacitance vs. Emitter-Base Voltage

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